



Abstract ID : 35

AP-XPS Study of surface potential variation during X-ray resonance

Content

The surface potential of semiconductor surfaces has been widely investigated with X-ray photoelectron spectroscopy (XPS). [1] The semiconductor surface potential is closely related to the band bending of semiconductor surfaces. For instance, with UV/Visible illumination, the semiconductor surface potential can be modulated through light-induced band bending reduction, resulting from the accumulation of photocarriers, i.e. surface photovoltage (SPV). [2]

To probe the light-induced modulation of surface potential at the X-ray regime, a tunable X-ray at synchrotron radiation and ambient-pressure XPS (AP-XPS) are applied to modulate the number of photocarriers of the system, Ar gas/MnO(001). As the photon energies are tuned to the near Mn 2p absorption resonance edge, the presence/variation of surface potential is monitored via the positions of Ar 2p gas phase peak near the surface as well as O 1s spectra of the MnO(001) surface.

In Fig. 1, our results show that the magnitude of the surface potential has a linear correlation with the X-ray absorption strength of the MnO(001). O 1s and Ar 2p photoelectron kinetic energies shift in the same magnitude. The observed linear correlation between X-ray absorption and photoelectron kinetic energy shift cannot be understood as a normal band bending reduction. Instead, the linear behavior can be related to the change of photoionization cross-section during the resonance. The effects of a) the X-ray-induced photocarriers and b) the resonant Auger emission in surface potential variation will be discussed together.

- References [1] Zhen Zhang and John T. Yates, Jr., Chemical reviews, 112, 5520 (2012) [2] Peter Schindler et al., ACS Energy Letter, 4, 2436 (2019)

Primary author: Mr SEO, Minsik (Gwangju Institute of Science and Technology)

Co-authors: Dr LIM, Hojoon (National Synchrotron Light Source II, Brookhaven National Laboratory); Dr KIM, Dongwoo (Gwangju Institute of Science and Technology); Dr SHIN, Hyunsuk (Gwangju Institute of Science and Technology); Dr NEMŠÁK, Slavomir (Advanced Light Source, Lawrence Berkeley National Laboratory); Prof. GALLET, Jean-Jacques (Synchrotron SOLEIL); Prof. BOURNEL, Fabrice (Synchrotron SOLEIL); Dr DUDY, Lenart (Synchrotron SOLEIL); Prof. MUN, Bongjin Simon (Gwangju Institute of Science and Technology)

Presenter: Mr SEO, Minsik (Gwangju Institute of Science and Technology)

